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APPLICATION NO	. F.	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/657,119	09/09/2003		Kazutaka Akiyama	09108.0003	9224	
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	N, HEND	ERSON, FARA	CAO, PHAT X			
LLP 901 NEW '	YORK AV	ENUE, NW	ART UNIT	PAPER NUMBER		
		20001-4413	2814			

DATE MAILED: 01/27/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	
		10/657,119	AKIYAMA, KAZUTAKA	
	Office Action Summary	Examiner	Art Unit	
		Phat X. Cao	2814	
 Period for	The MAILING DATE of this communication app Reply	pears on the cover sheet with the c	correspondence address	
A SHOI WHICH - Extensis after SI - If NO po - Failure Any rep	RTENED STATUTORY PERIOD FOR REPL' EVER IS LONGER, FROM THE MAILING Do ons of time may be available under the provisions of 37 CFR 1.1 K (6) MONTHS from the mailing date of this communication. eriod for reply is specified above, the maximum statutory period to to reply within the set or extended period for reply will, by statute ty received by the Office later than three months after the mailing patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tin will apply and will expire SIX (6) MONTHS from a, cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).	
Status				
2a)	tesponsive to communication(s) filed on <u>22 D</u> his action is FINAL . 2b) This ince this application is in condition for allowal losed in accordance with the practice under E	action is non-final. nce except for formal matters, pro		
Dispositio	n of Claims			
5)□ C 6)⊠ C 7)⊠ C 8)□ C	claim(s) 1-20 is/are pending in the application a) Of the above claim(s) 15-20 is/are withdraw claim(s) is/are allowed. claim(s) 1-4 and 6-12 is/are rejected. claim(s) 5,13 and 14 is/are objected to. claim(s) are subject to restriction and/or	vn from consideration.		
Application				
10)□ TI A R	ne specification is objected to by the Examine the drawing(s) filed on is/are: a) acception and acception are request that any objection to the eplacement drawing sheet(s) including the correction of the content of the co	epted or b) objected to by the drawing(s) be held in abeyance. Setion is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).	
Priority un	der 35 U.S.C. § 119			
a)⊠ 1 2 3	cknowledgment is made of a claim for foreign All b) Some * c) None of: Certified copies of the priority document Certified copies of the priority document Copies of the certified copies of the priority document application from the International Bureau the attached detailed Office action for a list	es have been received. Es have been received in Application of the second in the secon	on No ed in this National Stage	
2) Notice (3) Informa	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) tion Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Io(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D. 5) Notice of Informal F 6) Other:		·

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DETAILED ACTION

1. The Request for Continued Examination filed 12/22/05 is acknowledged.

Specification

2. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-4 and 10-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tanaka (US. 6,906,374) in view of Matsuoka et al (US. 6,809,364).

Regarding claims 1-2, Tanaka (Fig. 34) discloses a semiconductor device comprising: a semiconductor substrate 4; a first wiring 40 formed above the semiconductor substrate 4 with a first insulating film 36/32 interposed therebetween; an MIM capacitor having a lower metal electrode 54 or 11 (Fig. 1) (column 6, lines 15-16) and an upper metal electrode 58 (column 13, lines 47-50), and formed above the first insulating film 36/32; a second insulating film 48 formed to cover the MIM capacitor; and a guard ring 54 (see the rightmost 54 and column 11, lines 35-38) buried in the second insulating film 48 surrounding the MIM capacitor, wherein the guard ring 54 (rightmost 54) is provided such that the guard ring 54 is electrically insulated from the wirings and the MIM capacitor.

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Tanaka does not disclose a second wiring formed on the second insulating film 48.

However, Matsuoka (Fig. 22) teaches the forming of a capacitor, a first wiring 21 and a second wiring 26, the second wiring 26 is formed on a second insulating film 905/906 and connected to the first wiring 21 via a hole 25 formed in the second insulating film. Accordingly, it would have been obvious to form a second wiring on the second insulating film of Tanaka because as taught by Matsuoka, such forming of the second wiring would provide an additional wiring layer desired for the semiconductor device (column 8, lines 52-56).

Regarding claim 3, Tanaka (Fig. 34) further discloses the guard ring 54 formed of tungsten, which is the same material as the lower capacitor electrode (column 6, lines 15-23) and same material as the first wiring 40 (column 11, lines 16-18). Therefore, it would have been obvious to form the second wiring with tungsten which is the same material as the first wiring 40 and the guard ring 54 because tungsten is a well known conductor and commonly used for wiring because of its high conductivity characteristics.

Regarding claim 4, Tanaka (Fig. 34) further discloses the metal ring 54 is in an electrically floating state (no connection).

Regarding claim 10, because the MIM capacitor is completely surrounded by the guard ring 54, the guard ring 54 would inherently cut a seam generated in the second insulating film around the MIM capacitor.

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Regarding claim 11, Tanaka further discloses that a width of the guard ring 54 or a dimension of the tubular metal ring 54 is in the range of 0.1 to 1 um (column 9, lines 14-16).

Regarding claim 12, Tanaka's Fig. 34 further discloses a block insulating film 42 formed between the first and second insulating film to cover the first wiring 40.

4. Claims 6-9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tanaka and Matsuoka as applied to claim 1 above, and further in view of Nguyen et al (US. 2004/0092095).

Neither Tanaka nor Matsuoka disclose the second insulating film made of material having dielectric constant as claimed.

However, Nguyen (Fig. 1E) teaches the forming of an insulating film 104 surrounding an interconnect and made of materials including fluorine containing silicon oxide (FSG), carbon containing silicon oxide (SiOC), or porous silicon oxide (par. [0023]). Accordingly, it would have been obvious to form the second insulating film of Tanaka with the materials as set forth above because these dielectric materials having a very low dielectric constant, such as less than about 3, as taught by Nguyen (par. [0023]).

Allowable Subject Matter

5. Claims 5 and 13-14 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

See reasons of record.

Response to Arguments

6. a) Applicant argues that Tanaka (Fig. 34) does not suggest "a second insulating film formed to cover said MIM capacitor" because the second insulating film 48 cover the lower electrode 54, but not cover the upper electrode 58.

This argument is not persuasive because the limitation of having the second insulating film covering the upper electrode of the capacitor does not seem to be required by the claim language. Therefore, Tanaka does suggest "a second insulating film formed to cover said MIM capacitor" because the second insulating film 48 is clearly formed surround the upper electrode 58 and lower electrode 54 to cover the upper electrode 58 and lower electrode 54 to cover the upper electrode 58 and lower electrode 54 of the capacitor. Furthermore, Matsuoka (Fig. 22) also teaches the obviousness of forming a second insulating film 905/906 completely cover the capacitor structure 23 for the purpose of providing an additional wiring layer desired for the semiconductor device.

b) Regarding the combination of Tanaka and Matsuoka, Applicant argues that "The Examiner merely provided descriptions of how the references allegedly teach certain features without providing "clear and particular reasons" for the combination.

The examiner disagrees because the motivation as suggested by Matsuoka to modify the device of Tanaka is "clear and particular" to one skilled in the art.

Specifically, the examiner states "it would have been obvious to form a second wiring on the second insulating film of Tanaka because as taught by Matsuoka, such forming of the second wiring layer would provide an additional wiring layer desired for the semiconductor device (column 8, lines 52-56). The examiner recognizes that one

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skilled in the art would have no difficulty to understand the motivation provided by Matsuoka for combining the references as suggested.

c) Applicant (page 6) further argues that it is impossible to modify the device of Tanaka by forming an additional wiring lines (suggested by Matsuoka) in the peripheral circuit region.

It is noted that the arguments of counsel cannot take the place of evidence in the record. *In re Schulze*, 346 F. 2d 600, 602, 145 USPQ 716, 718 (CCPA 1965); *In re Geisler*, 116 F. 3d 1465, 43 USPQ2d 1362 (Fed. Cir. 1997). Attorney statements which are not evidence and which must be supported by an appropriate affidavit or declaration. Therefore, in view of teachings of Matsuoka, if Applicant belies that it is impossible to form an additional wiring lines in the peripheral circuit region of Tanaka's device, then Applicant is requested to support that position with facts.

d) Applicant (page 8) also argues that it would not obvious to combine Nguyen with Tanaka and Matsuoka because Nguyen does not teach the "guard ring".

This argument has no immediate apparent relevance to the issues presented by the rejection because Applicant cannot show nonobviousness by attacking references individually where the rejection is based upon a combination of references. *In re Young*, 403 F. 2d 754, 757, 159 USPQ 725, 728 (CCPA 1968). The examiner relies on the combined teachings of Nguyen with Tanaka and Matsuoka. Nguyen is not relied on for teaching a "guard ring". Tanaka discloses a "guard ring". Nguyen is relied on for showing the it was known to form an insulating film surrounding an interconnect and made of materials including fluorine containing silicon oxide, carbon containing silicon

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oxide, or porous silicon oxide (par. [0023]). The examiner thus regards Applicant's

assertions as constituting evidence that Applicant has failed to consider as a whole the

prior art teachings disclosed by the combining of the references.

7. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Phat X. Cao whose telephone number is 571-272-1703.

The examiner can normally be reached on M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Wael Fahmy can be reached on 571-272-1705. The fax phone number for

the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the

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PC

January 23, 2006

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